

78 Series Regulators

1A Output 78 series Regulators 500mA Output 78 series Regulators





No.12019ECT01

BA78□□Series,BA78M□□Series

Description

Features

- 1) Built-in over-current protection circuit and thermal shutdown circuit
- 2) High ripple rejection
- 3) Available TO220CP-3, TO252-3 package to a wide range application
- 4) Compatible replacement to competitor products
- 5) Various voltage lineup (5V, 6V, 7V, 8V, 9V, 10V, 12V, 15V, 18V, 20V, 24V)

Applications

Fixed voltage power supply for TV, Audio components, etc

●Line up

■1A BA78□□Series

Part Number	5V	6V	7V	8V	9V	10V	12V	15V	18V	20V	24V	Package
ВА78□□СР	0	0	0	0	0	0	0	0	0	0	0	TO220CP-3
BA78□□FP	0	0	0	0	0	0	0	0	0	0	0	TO252-3

■0.5A BA78M□□Series

20.07 By treining decines												
Part Number	5V	6V	7V	8V	9V	10V	12V	15V	18V	20V	24V	Package
ВА78М□□СР	0	0	0	0	0	0	0	0	0	0	0	TO220CP-3
BA78M□□FP	0	0	0	0	0	0	0	0	0	0	0	TO252-3

Output Voltage and Marking

Symbol		assignment of output voltage						
		Output voltage(V)		Output voltage(V)				
	05	5.0V typ.	12	12V typ.				
	06	6.0V typ.	15	15V typ.				
а	07	7.0V typ.	18	18V typ.				
	08	8.0V typ.	20	20V typ.				
	09	9.0V typ.	24V typ.					
	10	10.0V typ.						
		Package						
_		CP: TO220CP-3						
b		FP: TO252-3						

Symbol		assignment o	f outpu	ıt voltage				
		Output voltage(V)		Output voltage(V)				
	05	5.0V typ.	12	12V typ.				
a 06 07 08		6.0V typ.	15	15V typ.				
		7.0V typ.	18	18V typ.				
		8.0V typ.	20	20V typ.				
	09	9.0V typ.	24 24V typ.					
	10	10.0V typ.						
	ı	Package						
		CP : TO220CP-3						
b		FP : TO252-3						

● Absolute Maximum Rating (Ta=25°C)

BA78□□CP/FP, BA78M□□CP/FP

Para	meter	Symbol	Limits	Unit	
Power supply voltage		Vin	35	V	
Power Dissipation 1	TO220CP-3	Pd1	2 *1	W	
Power Dissipation i	TO252-3	Pui	1 *1	VV	
Dower Dissipation 2	TO220CP-3	Pd2	22 *2	W	
Power Dissipation 2	TO252-3	Puz	10 *2	VV	
Output Current	BA78□□	lo	1 *3	۸	
Output Current	BA78□□M	10	0.5 *3	A	
Operating Temperatur	re Range	Topr	-40~+85	°C	
Storage Temperature	Range	Tstg	-55~+150	°C	
Operating Junction Te	emperature Range	Tj	-40 ~ +150	°C	

- *1 Derating in done 16mW/°C(TO220CP-3), 8mW/°C(TO252-3) for temperatures above Ta=25°C
- *2 Derating in done 176mW/°C(TO220CP-3), 80mW/°C(TO252-3) for temperatures above Ta=25°C, Mounted on infinity Alminium heat sink.
- *3 Pd,ASO and Tjmax(150°C) should not be exceeded.

Operating Conditions(Ta=25°C, Pd should not be exceeded) BA78□□CP/FP

Para	Parameter		Min.	Max.	Unit.
	BA7805		7.5	25	
	BA7806		8.5	21	
	BA7807		9.5	22	
	BA7808		10.5	23	
Innut	BA7809		11.5	26	
Input Voltage	BA7810	Vin	12.5	25	V
voltage	BA7812		14.5	27	
	BA7815		17.5	30	
	BA7818		21	33	
	BA7820		23	33	Î
	BA7824		27	33	
Output C	urrent	lo	-	1	Α

BA78M□□CP/FP

Par	ameter	Symbol	Min.	Max.	Unit.
	BA78M05		7.5	25	
	BA78M06		8.5	21	
	BA78M07		9.5	22	
	BA78M08		10.5	23	
loout	BA78M09		11.5	26	
Input Voltage	BA78M10	Vin	12.5	25	V
vollage	BA78M12		14.5	27	
	BA78M15		17.5	30	
	BA78M18		21	33	
	BA78M20		23	33	
	BA78M24		27	33	
Output C	urrent	lo	-	0.5	Α

● Electrical Characteristics BA78M□□CP/FP

 $(Ta=25^{\circ}C, Vin=10V(05), 11V(06), 13V(07), 14V(08), 15V(09), 16V(10), 19V(12), 23V(15), 27V(18), 29V(20), 33V(24), \ lo=350 mA \ unless \ otherwise \ specified)$

Parameter	Symbol	Туре	Min	Limit Typ	Max	Unit	Condition
		05	4.8	5.0	5.2		
		06	5.75	6.0	6.25	1	
		07	6.7	7.0	7.3		
		08	7.7	8.0	8.3		
		09	8.6	9.0	9.4		
Output Voltage 1	Vo1	10	9.6	10.0	10.4	V	lo=350mA
		12	11.5	12.0	12.5		
		15	14.4	15.0	15.6		
		18	17.3	18.0	18.7		
		20	19.2	20.0	20.8		
		24	23.0	24.0	25.0		
		05	4.75	-	5.25		Vin=7.5~20V, Io=5mA~350mA
		06	5.7	-	6.3		Vin=8.5~21V, Io=5mA~350mA
		07	6.65	-	7.35		Vin=9.5~22V, Io=5mA~350mA
		08	7.6	-	8.4		Vin=10.5~23V, Io=5mA~350mA
		09	8.55	-	9.45		Vin=11.5~24V, Io=5mA~350mA
Output Voltage 2	Vo2	10	9.5	-	10.5	V	Vin=12.5~25V, Io=5mA~350mA
		12	11.4	-	12.6		Vin=15~27V, Io=5mA~350mA
		15	14.25	-	15.75		Vin=17.5~30V, lo=5mA~350mA
		18	17.1	-	18.9		Vin=21~33V, Io=5mA~350mA
		20	19.0	-	21.0		Vin=23~33V, lo=5mA~350mA
		24	22.8	-	25.2		Vin=27~33V, Io=5mA~350mA
		05	-	3	100		Vin=7~25V, lo=200mA
		06	-	3	100		Vin=8~25V, lo=200mA
		07 08	-	4	100 100		Vin=9~25V, Io=200mA Vin=10.5~25V, Io=200mA
		09	_	4	100		Vin=10.5* 25V, 10=200mA
Line Regulation 1	Reg.I1	10	_	5	100	mV	Vin=11.5~26V, Io=200mA
Line Regulation 1	ixeg.ii	12	_	5	100	IIIV	Vin=14.5~30V, lo=200mA
		15	_	6	100		Vin=17.5~30V, lo=200mA
		18	-	7	100		Vin=21~33V, Io=200mA
		20	_	8	100		Vin=23~33V, Io=200mA
		24	-	10	100		Vin=27~33V, Io=200mA
		05	-	1	50		Vin=8~12V, Io=200mA
		06	-	1	50		Vin=9~25V, Io=200mA
		07	-	1	50		Vin=10~25V, Io=200mA
		08	-	1	50		Vin=11~25V, Io=200mA
		09	-	2	50		Vin=12~25V, Io=200mA
Line Regulation 2	Reg.I2	10	-	2	50	mV	Vin=14~26V, Io=200mA
		12	-	3	50		Vin=16~30V, Io=200mA
		15	-	3	50		Vin=20~30V, Io=200mA
		18	-	3	50		Vin=24~33V, Io=200mA
		20	-	4	50		Vin=24~33V, Io=200mA
		24	-	5	50		Vin=28~33V, Io=200mA
		05	62	78	-		
		06	60	74	-		
		07	57	71	-		
		08	56	69	-		
D: 1 D : ::		09	56	67	-		
Ripple Rejection	R.R.	10	56	66	-	dB	ein=1Vrms, f=120Hz, Io=100mA
		12	55	63	-	1	
		15	54	60	-	-	
		18	53	58	-		
		20	53	58 55	-	1	
		24	50	55	-		
Temperature		05 06/07/08/09/10/12	-	-1.0	-	1	
Coefficient of	Tcvo	15/18	-	-0.5 -0.6	-	mV/°C	lo=5mA, Tj=0~125°C
Output Voltage		20/24		-0.6		-	
1		/11//4	-	-U./	-	İ	į .
Peak Output Current	lo-p	common	_	875	-	mA	Tj=25°C

● Electrical Characteristics BA78M□□CP/FP

 $(Ta=25^{\circ}\text{C}, Vin=10\text{V}(05), 11\text{V}(06), 13\text{V}(07), 14\text{V}(08), 15\text{V}(09), 16\text{V}(10), 19\text{V}(12), 23\text{V}(15), 27\text{V}(18), 29\text{V}(20), 33\text{V}(24), lo=350\text{mA} \text{ unless otherwise specified})$

Parameter	Symbol	Туре	Min	Limit Typ	Max	Unit	Condition
		05	-	20	100		
		06	-	20	120		
		07	-	20	140		
		08	-	20	160		
		09	-	20	180		
Load Regulation 1	Reg.L1	10	-	20	200	mV	Io=5mA~500mA
	1.09.21	12	-	20	240		
		15	-	20	300		
		18	_	20	360		
		20	_	20	400		
		24	_	20	480		
		05	-	10	50		
		06	_	10	60		
		07	_	10	70		
		08		10	80		
		09	-	10	90		
Load Regulation 2	Reg.L2	10	-	10	100	mV	Io-5mA~200mA
Loau Negulation 2	INGY.LZ	12	-	10	120	1117	Io=5mA~200mA
		15	-	10	150	1	
		18	-	10	180	1	
		20		10	200		
			-				
		24	-	10	240		+
		05 06	-	40	-		
		06	-	60 70	-		
			-		†		
		08	-	80	-		
Output Noise	.,	09	-	90	-	.,	
Voltage	Vn	10	-	100	-	μV	f=10Hz~100kHz
•		12	-	110	-		
		15	-	130	-		
		18	-	140	-		
		20	-	150	-		
		24	-	170	-		
Bias Current	lb	common	-	4.5	6.0	mA	Io=0mA
Bias Current Change1	lb1	common	-	-	0.5	mA	Io=5mA~350mA
		05	-	-	0.8		Vin:8~25V, Io=200mA
		06	-	-	8.0		Vin:9~25V, Io=200mA
		07	-	-	8.0		Vin:10~25V, Io=200mA
		08	-	-	0.8		Vin:10.5~25V, Io=200mA
		09	-	-	0.8		Vin:12~25V, Io=200mA
Bias Current Change 2	lb2	10	-	-	0.8	mA	Vin:13~25V, Io=200mA
		12	-	-	0.8		Vin:14.5~30V, Io=200mA
		15	-	-	0.8		Vin:17.5~30V, Io=200mA
		18	-	-	0.8		Vin:21~33V, Io=200mA
		20	-	-	0.8		Vin:23~33V, Io=200mA
		24	-	-	0.8		Vin:27~33V, Io=200mA
Short-Circuit	le-	05/06/07/08	-	0.4	-		Vin=25V
Output Current	los	09/10/12/15/18/20/24	-	0.17	-	Α	Vin=30V
•		05	-	9	-		
		06	-	10	-	1	
		07	-	11	-	1	
		08	-	12	-	1	
		09	-	13	-	1	
Output Resistance	Ro	10	_	14	_	mΩ	f=1kHz
	'	12	-	16	-	11122	
Output Resistance			1		i		İ
Output Resistance			_	10	_		
Output Resistance		15	-	19	-		
Output Resistance			- - -	19 22 25	-		

● Electrical Characteristics BA78□□CP/FP

 $(Ta=25^{\circ}\text{C}, Vin=10\text{V}(05), 11\text{V}(06), 13\text{V}(07), 14\text{V}(08), 15\text{V}(09), 16\text{V}(10), 19\text{V}(12), 23\text{V}(15), 27\text{V}(18), 29\text{V}(20), 33\text{V}(24), lo=500\text{mA} \text{ unless otherwise specified})$

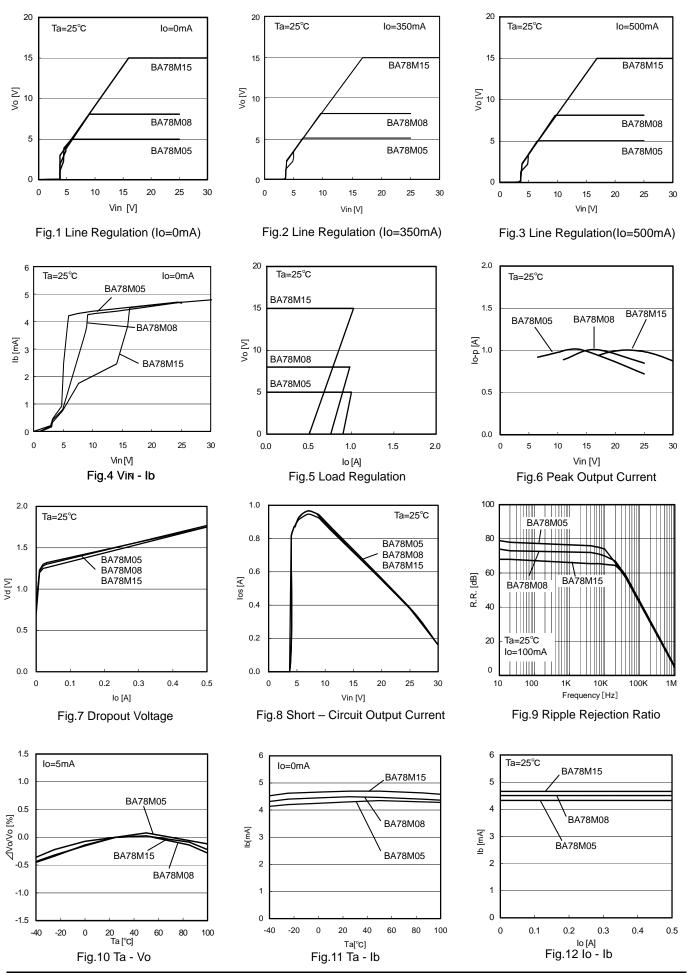
Parameter	Symbol	Туре	Min	Limit Typ	Max	Unit	Condition
		05	4.8	5.0	5.2		<u> </u>
		06	5.75	6.0	6.25		
		07	6.7	7.0	7.3		
		08	7.7	8.0	8.3		
		09	8.6	9.0	9.4		
Output Voltage 1	Vo1	10	9.6	10.0	10.4	V	Io=500mA
		12	11.5	12.0	12.5		
		15	14.4	15.0	15.6		
		18	17.3	18.0	18.7		
		20	19.2	20.0	20.8		
		24	23.0	24.0	25.0		
		05	4.75	-	5.25		Vin=7.5~20V, Io=5mA~1A
		06	5.7	-	6.3		Vin=8.5~21V, lo=5mA~1A
		07	6.65	-	7.35		Vin=9.5~22V, Io=5mA~1A
		08	7.6	-	8.4		Vin=10.5~23V, Io=5mA~1A
2tat \/alta.a.a. 0	1/-0	09	8.55	-	9.45	\ /	Vin=11.5~26V, Io=5mA~1A
Output Voltage 2	Vo2	10	9.5	-	10.5	V	Vin=12.5~25V, lo=5mA~1A
		12 15	11.4 14.25	-	12.6 15.75		Vin=15~27V, lo=5mA~1A
		18	14.25		18.9		Vin=17.5~30V, Io=5mA~1A Vin=21~33V, Io=5mA~1A
		20	19.0	-	21.0		Vin=23~33V, lo=5mA~1A
		24	22.8	-	25.2		Vin=27~33V, Io=5mA~1A
		05	-	3	100		Vin=7~25V, Io=500mA
		06	-	4	120		Vin=8~25V, Io=500mA
		07	-	5	140		Vin=9~25V, Io=500mA
		08	-	5	160		Vin=10.5~25V, Io=500mA
		09	-	6	180		Vin=11.5~26V, lo=500mA
ine Regulation 1	Reg.I1	10	-	7	200	mV	Vin=12.5~27V, Io=500mA
· ·		12	-	8	240		Vin=14.5~30V, Io=500mA
		15	-	9	300		Vin=17.5~30V, Io=500mA
		18	-	10	360		Vin=21~33V, Io=500mA
		20	-	12	400		Vin=23~33V, Io=500mA
		24	-	15	480		Vin=27~33V, Io=500mA
		05	-	1	50		Vin=8~12V, Io=500mA
		06	-	2	60		Vin=9~13V, Io=500mA
		07	-	2	70		Vin=10~15V, Io=500mA
		08	-	3	80		Vin=11~17V, Io=500mA
in a Damulatian O	D = = 10	09	-	4	90	\/	Vin=13~19V, Io=500mA
ine Regulation 2	Reg.I2	10	-	4	100	mV	Vin=14~20V, lo=500mA
		12 15	-	5 5	120 150		Vin=16~22V, Io=500mA Vin=20~26V, Io=500mA
		18	-	5	180		Vin=24~30V, Io=500mA
		20	-	7	200		Vin=26~32V, Io=500mA
		24	_	10	240		Vin=30~33V, Io=500mA
		05	62	78	-		00 001, 10-0001111
	1		59	73	-		
		06				1	1
				69	-		
		06 07 08	57 56	69 65	-		
		07	57				ain 4)/mag (400)
Ripple Rejection	R.R.	07 08	57 56	65	-	dB	ein=1Vrms, f=120Hz,
Ripple Rejection	R.R.	07 08 09	57 56 56	65 64	-	dB	ein=1Vrms, f=120Hz, Io=100mA
Ripple Rejection	R.R.	07 08 09 10	57 56 56 55	65 64 64		dB	
Ripple Rejection	R.R.	07 08 09 10 12 15	57 56 56 55 55 55 54 53	65 64 64 63 62 61	- - -	dB	
Ripple Rejection	R.R.	07 08 09 10 12 15 18	57 56 56 55 55 55 54 53	65 64 64 63 62 61 60		dB	
Ripple Rejection	R.R.	07 08 09 10 12 15 18 20 24	57 56 56 55 55 55 54 53	65 64 64 63 62 61 60 58	- - - -	dB	
	R.R.	07 08 09 10 12 15 18 20 24	57 56 56 55 55 54 53 53 50	65 64 64 63 62 61 60 58 -1.0		dB	
Femperature		07 08 09 10 12 15 18 20 24 05 06/07/08/09/10/12	57 56 56 55 55 54 53 53 50	65 64 64 63 62 61 60 58 -1.0			lo=100mA
Ripple Rejection Femperature Coefficient of Output Voltage	R.R.	07 08 09 10 12 15 18 20 24 05 06/07/08/09/10/12	57 56 56 55 55 54 53 53 50	65 64 63 62 61 60 58 -1.0 -0.5		dB mV/°C	
Temperature		07 08 09 10 12 15 18 20 24 05 06/07/08/09/10/12	57 56 56 55 55 54 53 53 50 -	65 64 64 63 62 61 60 58 -1.0			lo=100mA

● Electrical Characteristics BA78□□CP/FP

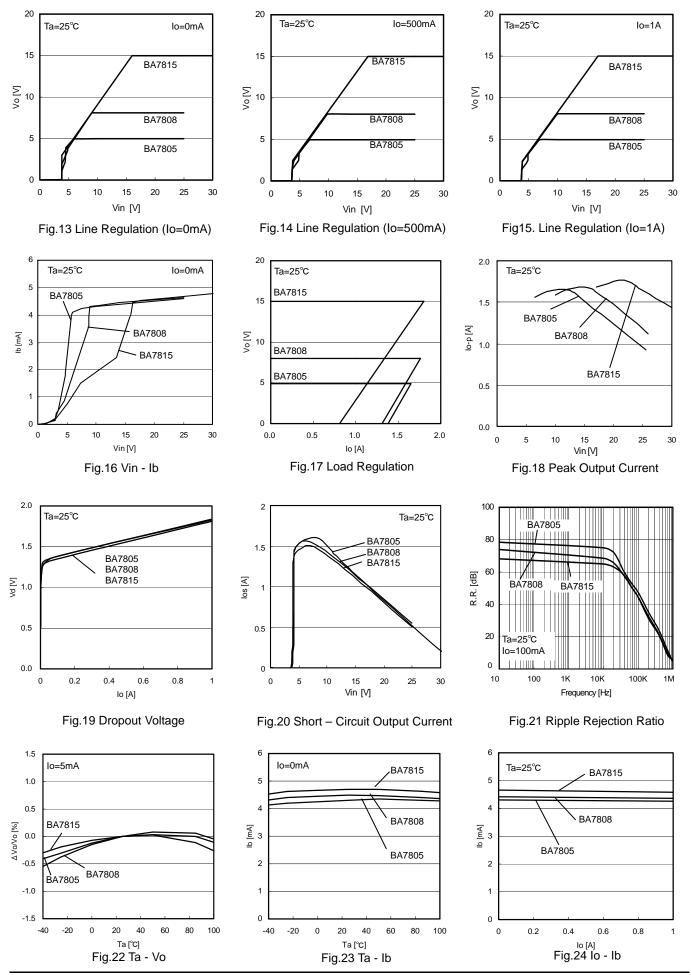
 $(Ta=25^{\circ}C, Vin=10V(05), 11V(06), 13V(07), 14V(08), 15V(09), 16V(10), 19V(12), 23V(15), 27V(18), 29V(20), 33V(24), Io=500mA \quad unless otherwise specified)$

(1a=25°C,Vin=10V(05),11V(00),100(01),11	(10),101(00),101(10),101(12	1	Limit	(20),001(21),io=500iii/(unless otherwise specified)		
Parameter	Symbol	Туре	Min		Max	Unit	Condition		
		05	-	Тур 15	100				
		06	-	16	120				
		07	-	17	140				
		08	-	19	160				
		09	-	20	180				
Load Regulation 1	Reg.L1	10	-	21	200	mV	Io=5mA~1A		
		12	-	23	200				
		15	-	27	300				
		18	-	30	360				
		20	-	32	400				
		24	-	37	480				
		05	-	5	50				
		06	_	6	60				
		07	+						
			-	6	70				
		08	-	7	80				
		09	-	8	90				
Load Regulation 2	Reg.L2	10	-	8	90	mV	Io=250mA~750mA		
		12	-	10	100				
		15	-	10	150				
		18	-	12	180				
		20	-	14	200				
		24	-	15	240				
		05	-	40	-				
		06	_	60	_				
		07		70					
			-		-				
		08	-	80	-				
Output Noise		09	-	90	-				
Voltage	Vn	10	-	100	-	μV	f=10Hz~100kHz		
· ······g·		12	-	110	-				
		15	-	125	-				
		18	-	140	-				
		20	-	150	-				
		24	-	180	-				
Bias Current	lb	common	-	4.5	8.0	mA	Io=0mA		
Bias Current Change 1	lb1	common	-	-	0.5	mA	Io=5mA~1A		
		05	-	-	0.8		Vin:8~25V, Io=500mA		
		06	-	_	0.8		Vin:8.5~25V, lo=500mA		
		07	_		0.8				
		08		-			Vin:9.5~25V, Io=500mA		
			-	-	0.8		Vin:10.5~25V, lo=500mA		
		09	-	-	0.8		Vin:11.5~26V, Io=500mA		
Bias Current Change 2	lb2	10	-	-	0.8	mA	Vin:12.5~27V, Io=500mA		
						mA	1\/in.44 E = .20\/ lo E00m \		
		12	-	-	0.8		Vin:14.5~30V, Io=500mA		
		15	-	-	0.8		Vin:17.5~30V, Io=500mA		
			-		0.8 0.8		Vin:17.5~30V, Io=500mA Vin:21~33V, Io=500mA		
		15	-	-	0.8		Vin:17.5~30V, Io=500mA		
		15 18	-	-	0.8 0.8 0.8		Vin:17.5~30V, Io=500mA Vin:21~33V, Io=500mA Vin:23~33V, Io=500mA		
Short-Circuit		15 18 20 24	- -	- - -	0.8 0.8		Vin:17.5~30V, Io=500mA Vin:21~33V, Io=500mA Vin:23~33V, Io=500mA Vin:27~33V, Io=500mA		
Short-Circuit Output Current	los	15 18 20 24 05/06/07/08	- - -	- - - - 0.6	0.8 0.8 0.8 0.8	A	Vin:17.5~30V, Io=500mA Vin:21~33V, Io=500mA Vin:23~33V, Io=500mA Vin:27~33V, Io=500mA Vin=25V		
Short-Circuit Output Current	los	15 18 20 24 05/06/07/08 09/10/12/15/18/20/24	- - - -	- - - 0.6 0.3	0.8 0.8 0.8 0.8	A	Vin:17.5~30V, Io=500mA Vin:21~33V, Io=500mA Vin:23~33V, Io=500mA Vin:27~33V, Io=500mA		
	los	15 18 20 24 05/06/07/08 09/10/12/15/18/20/24 05	- - - -	- - - - 0.6 0.3	0.8 0.8 0.8 0.8	A	Vin:17.5~30V, Io=500mA Vin:21~33V, Io=500mA Vin:23~33V, Io=500mA Vin:27~33V, Io=500mA Vin=25V		
	los	15 18 20 24 05/06/07/08 09/10/12/15/18/20/24 05 06	- - - -	- - - 0.6 0.3 9	0.8 0.8 0.8 0.8	А	Vin:17.5~30V, Io=500mA Vin:21~33V, Io=500mA Vin:23~33V, Io=500mA Vin:27~33V, Io=500mA Vin=25V		
	los	15 18 20 24 05/06/07/08 09/10/12/15/18/20/24 05 06 07	- - - -	- - - 0.6 0.3 9 10	0.8 0.8 0.8 0.8	А	Vin:17.5~30V, Io=500mA Vin:21~33V, Io=500mA Vin:23~33V, Io=500mA Vin:27~33V, Io=500mA Vin=25V		
	los	15 18 20 24 05/06/07/08 09/10/12/15/18/20/24 05 06 07		- - - 0.6 0.3 9 10 10	0.8 0.8 0.8 0.8 - - -	А	Vin:17.5~30V, Io=500mA Vin:21~33V, Io=500mA Vin:23~33V, Io=500mA Vin:27~33V, Io=500mA Vin=25V		
Output Current		15 18 20 24 05/06/07/08 09/10/12/15/18/20/24 05 06 07 08	- - - -	- - - 0.6 0.3 9 10 10	0.8 0.8 0.8 0.8		Vin:17.5~30V, Io=500mA Vin:21~33V, Io=500mA Vin:23~33V, Io=500mA Vin:27~33V, Io=500mA Vin=25V Vin=30V		
	los	15 18 20 24 05/06/07/08 09/10/12/15/18/20/24 05 06 07		- - - 0.6 0.3 9 10 10 10	0.8 0.8 0.8 0.8 - - -	A	Vin:17.5~30V, Io=500mA Vin:21~33V, Io=500mA Vin:23~33V, Io=500mA Vin:27~33V, Io=500mA Vin=25V		
Output Current		15 18 20 24 05/06/07/08 09/10/12/15/18/20/24 05 06 07 08		- - - 0.6 0.3 9 10 10	0.8 0.8 0.8 0.8 - - - - -		Vin:17.5~30V, Io=500mA Vin:21~33V, Io=500mA Vin:23~33V, Io=500mA Vin:27~33V, Io=500mA Vin=25V Vin=30V		
Output Current		15 18 20 24 05/06/07/08 09/10/12/15/18/20/24 05 06 07 08 09		- - - 0.6 0.3 9 10 10 10	0.8 0.8 0.8 0.8		Vin:17.5~30V, Io=500mA Vin:21~33V, Io=500mA Vin:23~33V, Io=500mA Vin:27~33V, Io=500mA Vin=25V Vin=30V		
Output Current		15 18 20 24 05/06/07/08 09/10/12/15/18/20/24 05 06 07 08 09 10 12		- - - 0.6 0.3 9 10 10 10 10	0.8 0.8 0.8 0.8 		Vin:17.5~30V, Io=500mA Vin:21~33V, Io=500mA Vin:23~33V, Io=500mA Vin:27~33V, Io=500mA Vin=25V Vin=30V		
Output Current		15 18 20 24 05/06/07/08 09/10/12/15/18/20/24 05 06 07 08 09 10 12 15		- - - 0.6 0.3 9 10 10 10 10 11 11 12	0.8 0.8 0.8 		Vin:17.5~30V, Io=500mA Vin:21~33V, Io=500mA Vin:23~33V, Io=500mA Vin:27~33V, Io=500mA Vin=25V Vin=30V		

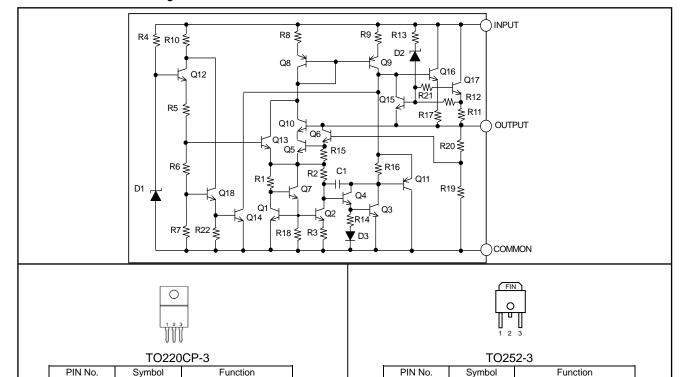
●BA78M□□ Characteristics data(Ta=25°C, Vin=10V(05), 14V(08), 23V(15) unless otherwise specified)



●BA78□□ Characteristics data (Ta=25°C, Vin=10V(05), 14V(08), 23V(15) unless otherwise specified)



Internal Circuit Structural Diagram



Protection Circuit

(1)Over-current protection circuit

INPUT

COMMON

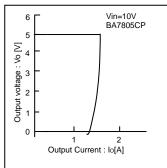
OUTPUT

When the maximum rating current or more is rushed, it controls the current ability and protects the IC from destruction.

Input terminal

Ground terminal

Output terminal



Input terminal

Non connection terminal

Output terminal

Ground terminal

INPUT

N.C.

OUTPUT

COMMON

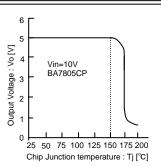
1

2

3

(2) Thermal shutdown circuit

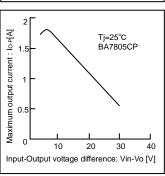
When the chip temperature of IC exceeds the setting temperature, the IC goes OFF, and it controls the IC not to be destroyed by the heat generation. It can be restored by being lowered the chip temperature of IC below the setting temperature.



(3) Safety operation area control circuit

It controls the output current in inverse proportion ratio to voltage difference (input-output).

When voltage difference becomes bigger, the IC will be destroyed in rush current. It protects the IC by controlling the current ability according to the voltage level.



Thermal design

Refer to the following thermal derating curves (Fig. 25, 26), when using in the status of Ta=25°C or more.

The characteristic of IC is greatly related to the operating temperature.

When it is used in over maximum junction temperature, the elements inside IC might become weaker and be destroyed. It is recommended to take into consideration thermal of IC.

Note that the temperatures are in the allowed temperature limits and operated within Pd.

It is necessary to operate it at junction temperature Timax or less to prevent IC from the thermal destruction.

Please operate IC within permissible loss Pd because the junction temperature Tj might become considerably a high temperature even if ambient temperature Ta is normal temperature (25°C).

Power consumption Pc(W) may be expressed by the equation shown below:

 $Pc=(Vin-Vo) \times Io + Vin \times Ib$ permissible loss $Pd \ge Pc$

 $lo \le \frac{Pd - Vin \times lb}{Vin - Vo}$

Vin : Input Voltage
Vo : Output Voltage
Io : Output Current
Ib : Bias current

Maximum Output current lo_{MAX} can be calculated in thermal design.

· Calculation example

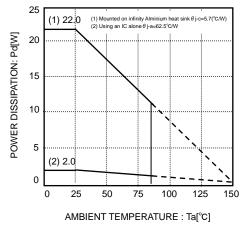
Ex.1) Ta=85°C, Vin =7.5V, Vo=5.0V

$$lo \le \frac{1.04 - 7.5 \times 4.5m}{7.5 - 5.0}$$

 $lo \le 400mA$

Using TO220CP-3 alone θ ja=62.5°C/W \rightarrow 16mW/°C Pd=1.04W at 85°C

Be sure to use this IC within a power dissipation at the range of operating temperature.



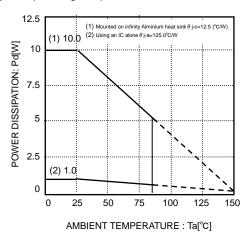


Fig.25 Thermal derating curve (TO220CP-3)

Fig.26 Thermal derating curve (TO252-3)

Terminal Setting and Cautions

INPUT

It is recommended that a capacitor (about 0.33uF) be inserted between INPUT and COMMON. The value of capacitor is designed suitable for the actual application.

OUTPUT

It is recommended that a capacitor (about 0.1uF) be inserted between OUTPUT and COMMON.

A tantalum capacitor can also be used for this pin because insufficient capacitors may cause oscillation by a temperature change.

COMMON

Keep the no voltage drop between Ground level of set board and IC.

When there is the voltage difference, setting voltage becomes inaccuracy and unstable.

It is recommended to connect by wide, short pattern, and lower the inpedance.

Notes for use

(1) Absolute Maximum Ratings

While utmost care is taken to quality control of this product, any application that may exceed some of the absolute maximum ratings including the voltage applied and the operating temperature range may result in breakage. If broken, short-mode or open-mode may not be identified. So if it is expected to encounter with special mode that may exceed the absolute maximum ratings, it is requested to take necessary safety measures physically including insertion of fuses.

(2) Ground voltage

Make setting of the potential of the GND terminal so that it will be maintained at the minimum in any operating state. Furthermore, check to be sure no terminals are at a potential lower than the GND voltage including an actual electric transient.

(3) Thermal design

When you do the kind of use which exceeds Pd, It may be happened to deteriorating IC original quality such as decrease of electric current ability with chip temperature rise. Do not exceed the power dissipation (Pd) of the package specification rating under actual operation, and please design enough temperature margins.

(4) Short-circuiting between terminals, and mismounting

When mounting to pc board, care must be taken to avoid mistake in its orientation and alignment. Failure to do so may result in IC breakdown. Short-circuiting due to foreign matters entered between output terminals, or between output and power supply or GND may also cause breakdown.

(5) Operation in Strong electromagnetic field

Be noted that using the IC in the strong electromagnetic radiation can cause operation failures.

(6) Inspection with the IC set to a pc board

If a capacitor must be connected to the pin of lower impedance during inspection with the IC set to a pc board, the capacitor must be discharged after each process to avoid stress to the IC. For electrostatic protection, provide proper grounding to assembling processes with special care taken in handling and storage. When connecting to jigs in the inspection process, be sure to turn OFF the power supply before it is connected and removed.

(7) Input to IC terminals

This is a monolithic IC with P⁺ isolation between P-substrate and each element as illustrated below. This P-layer and the N-layer of each element form a P-N junction, and various parasitic element are formed.

If a resistor is joined to a transistor terminal as shown in Fig 28.

OP-N junction works as a parasitic diode if the following relationship is satisfied;

GND>Terminal A (at resistor side), or GND>Terminal B (at transistor side); and

Oif GND>Terminal B (at NPN transistor side),

a parasitic NPN transistor is activated by N-layer of other element adjacent to the above-mentioned parasitic diode. The structure of the IC inevitably forms parasitic elements, the activation of which may cause interference among circuits, and/or malfunctions contributing to breakdown. It is therefore requested to take care not to use the device in such manner that the voltage lower than GND (at P-substrate) may be applied to the input terminal, which may result in activation of parasitic elements.

(8) Ground wiring pattern

If small-signal GND and large-current GND are provided, It will be recommended to separate the large-current GND pattern from the small-signal GND pattern and establish a single ground at the reference point of the set PCB so that resistance to the wiring pattern and voltage fluctuations due to a large current will cause no fluctuations in voltages of the small-signal GND. Pay attention not to cause fluctuations in the GND wiring pattern of external parts as well.

(9) Thermal shutdown circuit

A temperature control circuit is built in the IC to prevent the damage due to overheat. Therefore, the output is turned off when the thermal circuit works and is turned on when the temperature goes down to the specified level.

But, built-in the IC a temperature control circuit to protect itself, and avoid the design used the thermal protection.

(10) Over current protection circuit

The over-current protection circuits are built in at output, according to their respective current outputs and prevent the IC from being damaged when the load is short-circuited or over-current. But, these protection circuits are effective for preventing destruction by unexpected accident. When it's in continuous protection circuit moving period don't use please. And for ability, because this chip has minus characteristic, be careful for heat plan.

(11) There is a possibility to damage an internal circuit or the element when Vin and the voltage of each terminal reverse in the application. For instance, Vin is short-circuited to GND etc. with the charge charged to an external capacitor. Please use the capacitor of the output terminal with 1000μF or less. Moreover, the Vin series is recommended to insert the diode of the by-pass the diode of the backflow prevention or between each terminal and Vin.

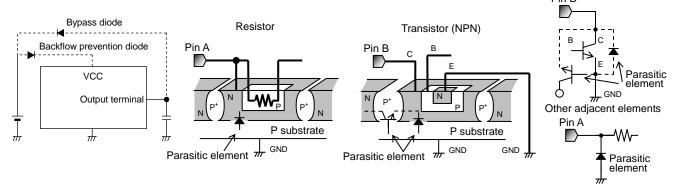
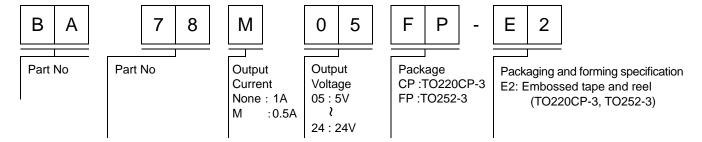


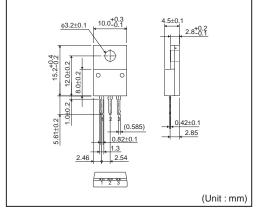
Fig.27 Bypass Diode

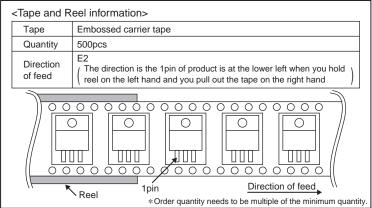
Fig.28 Simplified structure of monorisic IC

Ordering part number

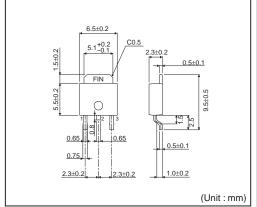


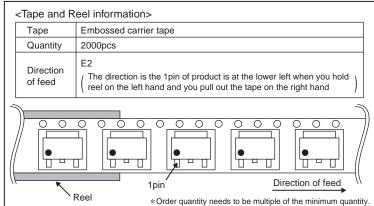
TO220CP-3





TO252-3





Notice

Precaution on using ROHM Products

Our Products are designed and manufactured for application in ordinary electronic equipments (such as AV equipment, OA equipment, telecommunication equipment, home electronic appliances, amusement equipment, etc.). If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment (Note 1), transport equipment, traffic equipment, aircraft/spacecraft, nuclear power controllers, fuel controllers, car equipment including car accessories, safety devices, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

(Note1) Medical Equipment Classification of the Specific Applications

JAPAN	USA	EU	CHINA
CLASSⅢ	CI ACCIII	CLASS II b	СГУССШ
CLASSIV	CLASSII	CLASSⅢ	CLASSⅢ

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 - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
 - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation (Pd) depending on Ambient temperature (Ta). When used in sealed area, confirm the actual ambient temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used; if flow soldering method is preferred, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

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- If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
- You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

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This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

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- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
 - [a] the Products are exposed to sea winds or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
 - [b] the temperature or humidity exceeds those recommended by ROHM
 - the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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QR code printed on ROHM Products label is for ROHM's internal use only.

Precaution for Disposition

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